EVERLIGHT

DATASHEET

4 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER EL817-G Series



Features:

- Compliance Halogens Free
- (Br < 900 ppm, Cl < 900 ppm, Br+Cl < 1500 ppm) • Current transfer ratio
- (CTR: 50~600% at IF = 5mA, VCE = 5V)
- High isolation voltage between input and output (Viso = 5000Vrms)
- Creepage distance > 7.62mm
- Operating temperature up to +110°C
- Compact small outline package
- Compliance with EU REACH.
- •The product itself will remain within RoHS compliant version
- UL and cUL approved(No.E214129)
- VDE approved (No.132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved
- CQC approved

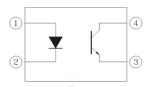
Description

The EL817-G series of devices each consist of an infrared emitting diodes, optically coupled to a phototransistor detector. They are packaged in a 4-pin DIP package and available in wide-lead spacing and SMD option.

Applications

- Programmable controllers
- System appliances, measuring instruments
- Telecommunication equipments
- Home appliances, such as fan heaters, etc.
- Signal transmission between circuits of different potentials and impedances

<u>Schematic</u>



- **Pin Configuration**
- 1. Anode
- 2. Cathode
- Emitter
 Collector

Absolute Maximum Ratings (Ta=25°C)

	Parameter	Symbol	Rating	Unit
	Forward current	I _F	60	mA
	Peak forward current (1us, pulse)	I _{FP}	1	А
Input	Reverse voltage	VR	6	V
	Power dissipation	D	100	mW
	Derating factor (above T _a = 100°C)	PD	2.9	mW/°C
Output	Power dissipation		150	mW
	Derating factor (above $T_a = 100^{\circ}C$)	Pc	5.8	mW/°C
	Collector current	Ic	50	mA
	Collector-Emitter voltage	V _{CEO}	80	V
	Emitter-Collector voltage	V _{ECO}	7	V
Total Powe	r Dissipation	P _{TOT}	200	mW
Isolation V	oltage*1	V _{ISO}	5000	V rms
Operating	Temperature	T _{OPR}	-55 to 110	°C
Storage Te	emperature	T _{STG}	-55 to 125	°C
Soldering	Temperature* ²	T _{SOL}	260	°C

Notes:

*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 are shorted together, and pins 3, 4 are shorted together. *2 For 10 seconds

Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

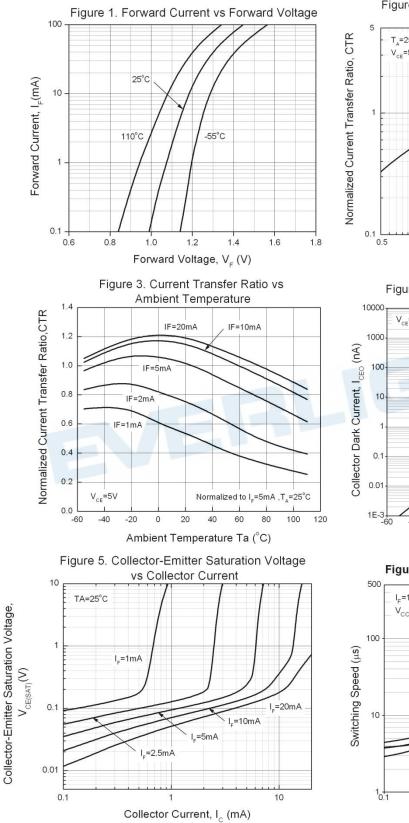
Input							
Para	meter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward Voltage		VF	-	1.2	1.4	V	$I_F = 20 \text{mA}$
Reverse Cu	urrent	IR	-	-	10	μA	$V_R = 4V$
Input capac	citance	Cin	-	30	250	pF	V = 0, f = 1kHz
Output							
Para	meter	Symbol	Min	Тур.	Max.	Unit	Condition
Collector-Er current	nitter dark	I _{CEO}	-	-	100	nA	$V_{CE} = 20V$, $I_F = 0mA$
Collector-E breakdown		BV _{CEO}	80	-	-	V	$I_{C} = 0.1 \text{mA}$
Emitter-Coll breakdown		BV_{ECO}	7	-	-	V	I _E = 0.1mA
Transfer Ch	aracteristics						
Para	meter	Symbol	Min	Тур.	Max.	Unit	Condition
	EL817		50		600		
	EL817A	CTR	80	_	160	- %	I _F = 5mA ,V _{CE} = 5V
Current	EL817B		130	-	260		
Transfer	EL817C		200	-	400		
ratio	EL817D		300	-	600		
	EL817X		100	-	200		
	EL817Y		150	-	300		
Collector-E saturation v		V _{CE(sat)}	-	0.1	0.2	V	$I_F = 20mA$, $I_C = 1mA$
	5.1.5.9.5						
Isolation res	-	R _{IO}	5×10 ¹⁰	-	-	Ω	V _{IO} = 500Vdc, 40~60% R.H.
Isolation res	sistance	R _{IO} C _{IO}	5×10 ¹⁰	- 0.6	- 1.0	Ω pF	
	sistance pacitance						40~60% R.H.
Floating ca	sistance pacitance	C _{IO}		0.6		pF	40~60% R.H. V _{IO} = 0, f = 1MHz V _{CE} = 5V, I _C = 2mA

* Typical values at Ta = 25°C

DATASHEET 4PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER EL817-G Series

EVERLIGHT

Typical Electro-Optical Characteristics Curves



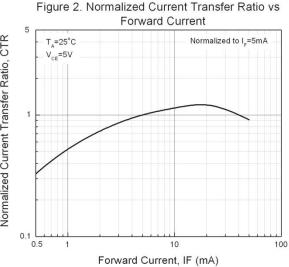
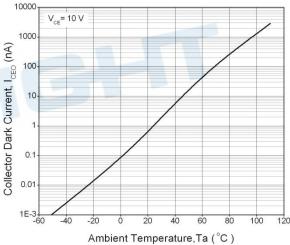
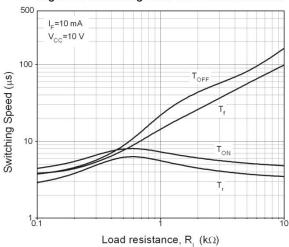


Figure 4. Dark Current vs Ambient Temperature







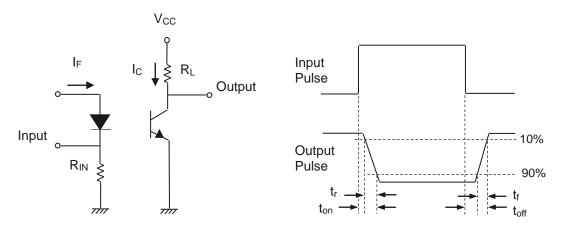


Figure 7. Switching Time Test Circuit & Waveforms



Order Information

Part Number

EL817X(Y)(Z)-FVG

Note

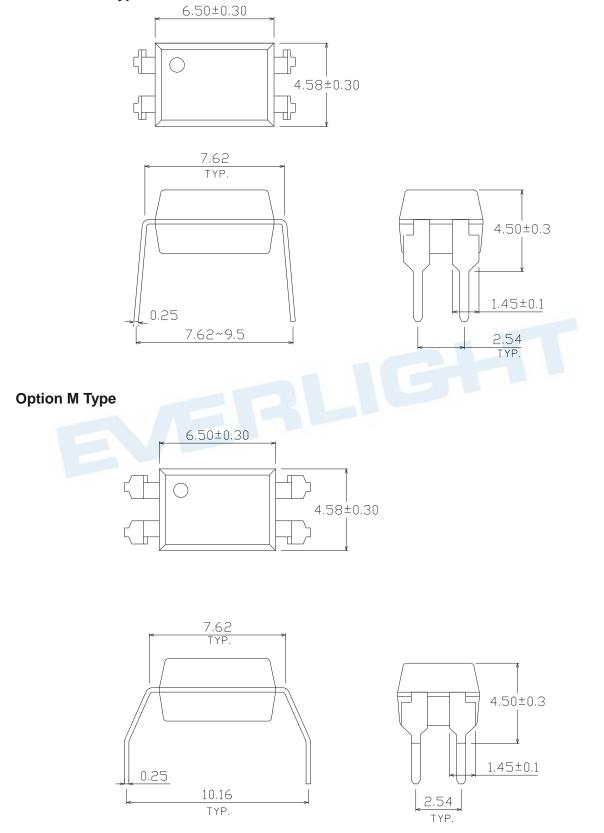
- X = Lead form option (S1, S2, M or none)
- Y = CTR Rank (A, B, C, D, X, Y or none)
- Z = Tape and reel option (TU, TD or none)
- F = Lead frame option (F: Iron, None: copper)
- V = VDE safety (optional)
- G = Halogens free

Option	Description	Packing quantity
None	Standard DIP-4	100 units per tube
М	Wide lead bend (0.4 inch spacing)	100 units per tube
S1 (TU)	Surface mount lead form (low profile) + TU tape & reel option	1500 units per reel
S1 (TD)	Surface mount lead form (low profile) + TD tape & reel option	1500 units per reel
S2 (TU)	Surface mount lead form (low profile) + TU tape & reel option	2000 units per reel
S2 (TD)	Surface mount lead form (low profile) + TD tape & reel option	2000 units per reel

EVERLIGHT

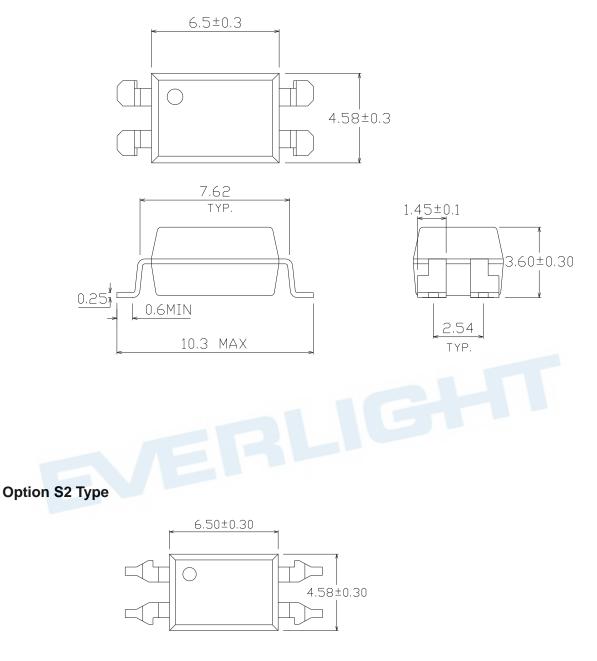
Package Dimension (Dimensions in mm)

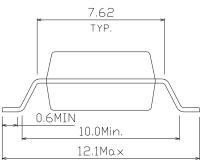
Standard DIP Type

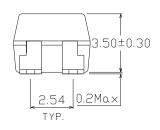


EVERLIGHT

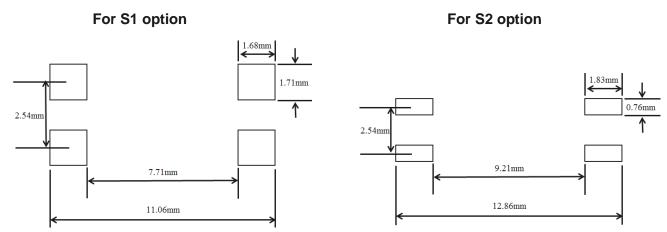
Option S1 Type







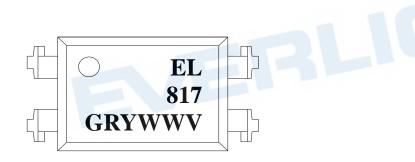
Recommended pad layout for surface mount leadform



Notes

Suggested pad dimension is just for reference only. Please modify the pad dimension based on individual need.

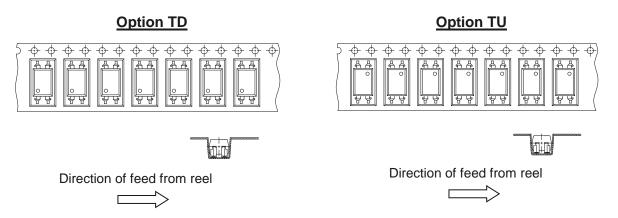
Device Marking



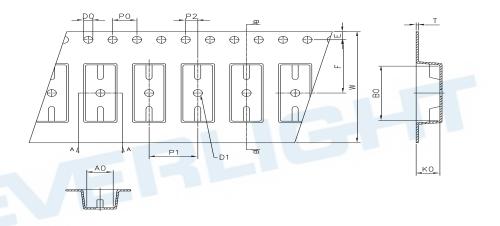
Notes

EL	denotes EVERLIGHT
817	denotes Device Number
G	denotes Green part
R	denotes CTR Rank (A, B, C, D, X, Y or none)
Y	denotes 1 digit Year code
WW	denotes 2 digit Week code
V	denotes VDE (optional)

Tape & Reel Packing Specifications



Tape dimensions

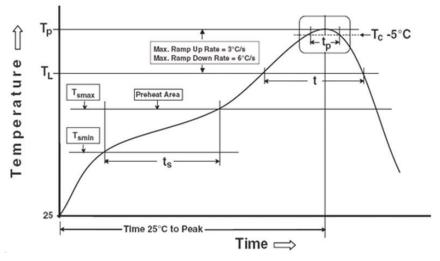


Dimension No.	Ao	Во	Do	D1	Е	F
Dimension (mm) S1	4.90±0.1	10.40±0.1	1.5±0.1	1.50±0.1	1.75±0.1	7.50±0.1
Dimension (mm) S2	4.88±0.1	12.55±0.1	1.5±0.1	1.50±0.1	1.75±0.1	11.5±0.1
Dimension No.	Ро	P1	P2	t	W	Ко
Dimension No. Dimension (mm) S1	Po 4.00±0.1	P1 8.00±0.1	P2 2.00±0.1	t 0.40±0.1	W 16.00±0.3	Ko 4.60±0.1

Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

Preheat

1 ronout	
Temperature min (T _{smin})	150 °C
Temperature max (T _{smax})	200°C
Time (T_{smin} to T_{smax}) (t_s) Average ramp-up rate (T_{smax} to T_p)	60-120 second 3 °C/second n
Other	
Liquidus Temperature (T∟)	217 °C
Time above Liquidus Temperature (t L)	60-100 sec
Peak Temperature (T _P)	260°C
Time within 5 °C of Actual Peak Temperature: T_P - 5°C	30 s
Ramp- Down Rate from Peak Temperature	6°C /second n
Time 25°C to peak temperature Reflow times	8 minutes ma 3 times

Reference: IPC/JEDEC J-STD-020D

EVERLIGHT

nds max

max. ax.

DISCLAIMER

- 1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 2. The graphs shown in this datasheet are representing typical data only and do not show guaranteed values.
- 3. When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
- 4. These specification sheets include materials protected under copyright of EVERLIGHT. Reproduction in any form is prohibited without the specific consent of EVERLIGHT.
- 5. This product is not intended to be used for military, aircraft, automotive, medical, life sustaining or life saving applications or any other application which can result in human injury or death. Please contact authorized Everlight sales agent for special application request.
- 6. Statements regarding the suitability of products for certain types of applications are based on Everlight's knowledge of typical requirements that are often placed on Everlight products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Everlight's terms and conditions of purchase, including but not limited to the warranty expressed therein.

单击下面可查看定价,库存,交付和生命周期等信息

>>Amphenol(安费诺)